Thyristor Semiconductor Device - Page 1 of 1



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Inclosure	Material:

Metal

Overall Length:

0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited

Current Rating Per Characteristic:

2.00 amperes zero-gate-voltage source current horsepower metric

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

Special Features:

Internal junction configuration arrangement pnpn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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